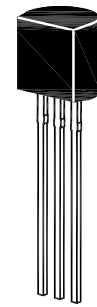


BC307...BC308

PNP Silicon Epitaxial Planar Transistor

for switching and amplifier applications



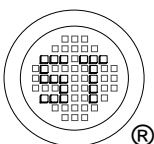
1. Collector 2. Base 3. Emitter
TO-92 Plastic Package

Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

| Parameter | Symbol | BC307 | BC308 | Unit |
|---------------------------|------------|---------------|-------|------------------|
| Collector Base Voltage | $-V_{CB0}$ | 50 | 30 | V |
| Collector Emitter Voltage | $-V_{CEO}$ | 45 | 25 | V |
| Emitter Base Voltage | $-V_{EBO}$ | 5 | | V |
| Collector Current | $-I_C$ | 100 | | mA |
| Total Power Dissipation | P_{tot} | 500 | | mW |
| Junction Temperature | T_j | 150 | | $^\circ\text{C}$ |
| Storage Temperature Range | T_s | - 55 to + 150 | | $^\circ\text{C}$ |

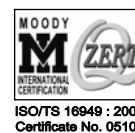
Characteristics at $T_a = 25\text{ }^\circ\text{C}$

| Parameter | Symbol | Min. | Max. | Unit | |
|---|--------|----------------|------|------|-----|
| DC Current Gain at $-V_{CE} = 5\text{ V}$, $-I_C = 2\text{ mA}$ Current Gain Group | A | h_{FE} | 120 | 220 | - |
| | B | h_{FE} | 180 | 460 | - |
| | C | h_{FE} | 380 | 800 | - |
| Collector Base Cutoff Current at $-V_{CB} = 50\text{ V}$ at $-V_{CB} = 30\text{ V}$ | BC307 | $-I_{CBO}$ | - | 15 | nA |
| | BC308 | | - | 15 | |
| Collector Emitter Breakdown Voltage at $-I_C = 2\text{ mA}$ | BC307 | $-V_{(BR)CEO}$ | 45 | - | V |
| | BC308 | | 25 | - | |
| Emitter Base Breakdown Voltage at $-I_E = 100\text{ }\mu\text{A}$ | | $-V_{(BR)EBO}$ | 5 | - | V |
| Collector Emitter Saturation Voltage at $-I_C = 10\text{ mA}$, $-I_B = 0.5\text{ mA}$ at $-I_C = 100\text{ mA}$, $-I_B = 5\text{ mA}$ | | $-V_{CE(sat)}$ | - | 0.3 | V |
| | | | - | 0.6 | |
| Base Emitter On Voltage at $-V_{CE} = 5\text{ V}$, $-I_C = 2\text{ mA}$ | | $-V_{BE(on)}$ | 0.55 | 0.7 | V |
| Current Gain Bandwidth Product at $-V_{CE} = 5\text{ V}$, $-I_C = 10\text{ mA}$, $f = 100\text{ MHz}$ | | f_T | 100 | - | MHz |
| Collector Base Capacitance at $-V_{CB} = 10\text{ V}$, $f = 1\text{ MHz}$ | | C_{cb} | - | 6 | pF |



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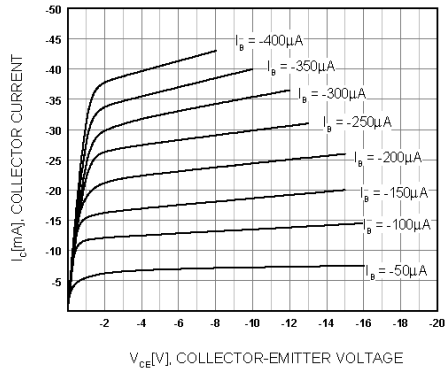


Figure 1. Static Characteristic

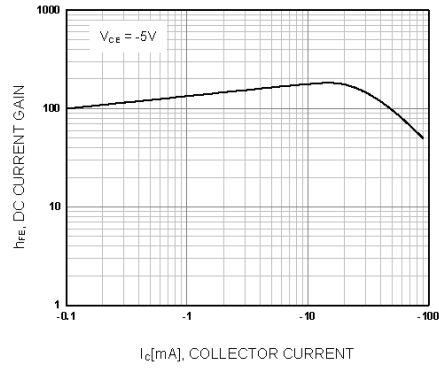


Figure 2. DC current Gain

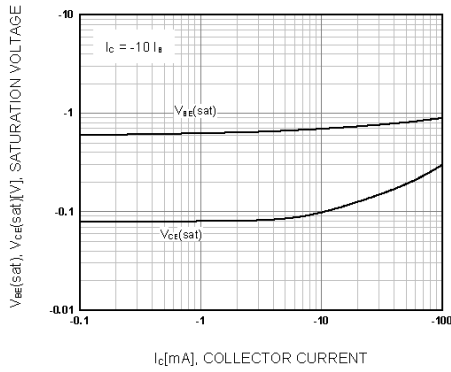


Figure 3. Base-Emitter Saturation Voltage
Collector-Emitter Saturation Voltage

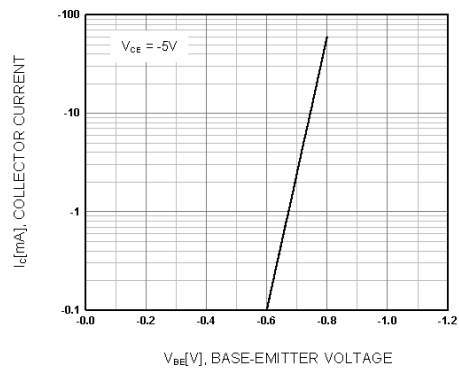


Figure 4. Base-Emitter Capacitance

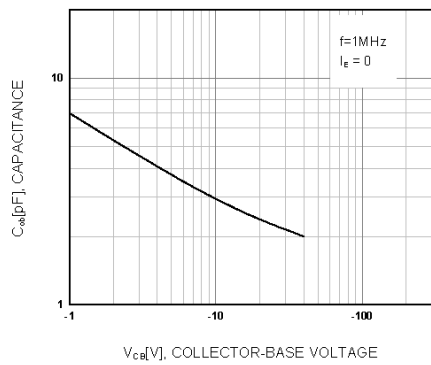


Figure 5. Collector Output Capacitance

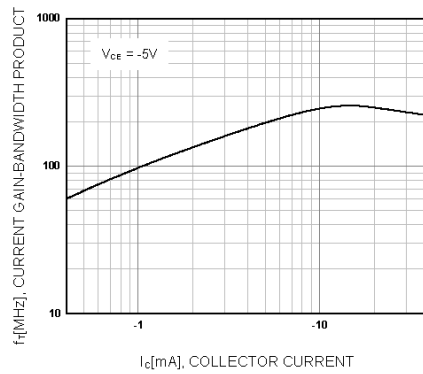
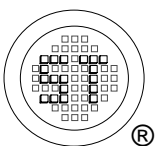
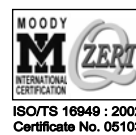


Figure 6. Current Gain Bandwidth Product



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